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	REPORT DOCUMENTATION PAGE	READ INSTRUCTIONS BEFORE COMPLETING FORM
$(t^{i_i})$	HDL-TM-81-13 - AD-A101	3. RECIPIENT'S CATALOG NUMBER  5.8.4
	Bipolar Transistor and Diode Failure to Electrical TransientsPredictive Failure Modeling versus Experimental Damage Testing, 20 AFWL Transistor and Diode Failure Modele	S. TYPE OF REPORT & PERIOD COVERED Technical Memorandum 6. PERFORMING ORG. REPORT NUMBER 8. CONTRACT OR GRANT NUMBER(a)
	7. Author(s) Michael J./Vrabel Performing Organization name and address	10. PROGRAM EI EMENT PROJECT TASK
	Harry Diamond Laboratories 2800 Powder Mill Road Adelphi, MD 20783	10. PROGRAM ELEMENT PROJECT, TASK AREA WORK UNIT NUMBERS Program Ele: 6.21.20.A
:	11. CONTROLLING OFFICE NAME AND ADDRESS U.S. Army Materiel Research and Development Command Alexandria, VA 22333	Jun 981  TS. NUMBER OF PAGES  36
	14. MONITORING AGENCY NAME & ADDRESS(II different from Controlling Office)	UNCLASSIFIED
		15a. DECLASSIFICATION/DOWNGRADING SCHEDULE
	Approved for public release; distrib	oution unlimited.
	17. DISTRIBUTION STATEMENT (of the abstract entered in Block 20, if different from	n Report)
	DRCMS Code: 612120.H.250011 DA Project: 1L162126AH25 HDL Project: 7750E2	
	19. KEY WORDS (Continue on reverse side if necessary and identify by block number) Semiconductor damage Component failure Junction capacitance damage model Failure modeling	
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## 1. INTRODUCTION

A recent Air Force Weapons Laboratory (AFWL) document, Electronic Component Modeling and Testing Program, AFWL-TR-78-62 Pt.1 (March 1980), contains a new model for predicting bipolar transistor and diode failure for reverse junction bias. This paper examines the capability of this model using as a baseline a library of experimental damage data for devices from the front ends of an array of Army tactical multichannel radios.

## 2. EXAMINATION

The new model is implemented as follows:

(1) Calculate doping concentration from room temperature breakdown voltage:

$$N_D = 4.49 \times 10^{18} V_{BD}^{-1.5}$$

where

 $N_D$  = doping concentration on lightly doped side of junction (inverse cubic centimeters),

V<sub>BD</sub> = room temperature breakdown voltage (volts).

(2) Calculate breakdown voltage at critical failure temperature:

$$V_{BDC} = 4.07 \times 10^{12} N_D^{-0.67}$$

where

VBDC = breakdown voltage at critical failure temperature
 (volts).

(3) Calculate space charge resistivity:

$$\rho_{SC} = 2.48 \times 10^{25} N_D^{-1.8}$$

where

 $\rho_{SC}$  = space charge resistivity (ohm-square centimeters).

(4) Calculate bulk resistivity:

$$\rho_{BLK} = 3.61 \times 10^{10} N_D^{-0.61}$$

where

 $\rho_{BLK}$  = bulk resistivity (ohm-square centimeters).

(5) Calculate failure current density at 100 ns:

Emitter-to-base junction:

$$J_F = 3.84 \times 10^{-11} N_D^{0.88}$$

where

 $J_F$  = failure current density at 100 ns (amperes/square centimeter).

Collector-to-base or diode junction:

$$J_F = 8.25 \times 10^{-11} N_D^{0.88}$$
.

(6) Calculate junction area:

Emitter-to-base junction:

# Priority 1

Area = 
$$1.47 \left(2.3 \times 10^{-6} \text{C}_{\text{O}_{\text{EB}}} \text{V}_{\text{BD}}^{0.67}\right)^{1.05}$$
,

where

 $C_{O_{EB}} = C_{RE}V_{RF}^{0.5} = corrected emitter-to-base capacitance (picofarads),$ 

 $C_{RE}$  = emitter-to-base capacitance at rated voltage (picofarads),

 $V_{RF}$  = rated voltage (volts),

 $V_{\rm BD}$  = rated emitter-to-base breakdown voltage (volts).

# Priority 2

Area = 
$$6.34 \times 10^{-4} I_{MAX}^{0.82}$$
,

where

I\_MAX = maximum rated transistor collector current (amperes).

# Priority 3

Area = 
$$8.75 \times 10^{-3} \left(2 \times 10^{-6} C_{O_{CB}} v_{BD_{CB}}^{0.83}\right)^{0.58}$$

where

 $C_{O_{CB}} = C_{RC}V^{0.333} = corrected collector~to-base capacitance (picofarads),$ 

 $C_{RC}$  = collector-to-base capacitance at rated voltage (picofarads),

 $V_{RC}$  = rated voltage for collector-to-base capacitance (volts),

 $v_{\mathrm{BD}_{\mathrm{CB}}}$  = collector-to-base breakdown voltage (volts).

# Priority 4

Area = 
$$1.19 \times 10^{-2} \theta_{.TC}^{-0.94}$$
,

where

 $\theta_{JC}$  = junction-to-case thermal resistance (degrees Celsius/watt).

# Priority 5

Area = 
$$2.790^{-1}.70$$

where

 $\theta_{JA}$  = junction-to-ambient thermal resistance (degrees Celsius/watt).

Collector-to-base junction:

Priority 1

Area =  $0.0478 \frac{-0.89}{30}$ .

Priority 2

Area =  $2.72 \times 10^{-3} I_{MAX}^{0.62}$ .

Priority 3

Area =  $3.630 \frac{-1}{JA}^{-47}$ .

Priority 4

Area =  $1.13 \times 10^{-2} \left(2 \times 10^{-6} c_{O_{CB}} v_{BD}^{0.83}\right)^{0.39}$ .

Diode junction:

Priority 1

Area =  $8.1 \times 10^{-3} I_{MAX}^{1.16}$ 

where

 $I_{MAX}$  = maximum rated diode currents (amperes) for Zener diodes =  $I_{ZM}V_{Z}$ ,

 $I_{ZM}$  = maximum rated Zener current (amperes),

 $V_Z$  = rated Zener voltage (volts).

Priority 2

Area =  $0.458 \left(2 \times 10^{-6} C_{O_D} V_{BD}^{0.83}\right)^{0.83}$ ,

where

 $c_{OD} = c_{RD} v_{RD}^{0.333}$ 

CRD = diode junction capacitance at rated voltage (picofarads),

 $V_{RD}$  = rated voltage (volts).

# Priority 3

Area = 
$$0.4896 \frac{1}{JL}$$
.

where

 $\theta_{JL}$  = junction-to-lead thermal resistance (degrees Celsius/watt).

# Priority 4

Area = 
$$1.9630_{JA}^{-1} \cdot ^{32}$$
.

(7) Calculate bulk resistance, space charge resistance, and failure current at 100 ns:

$$R_{BLK} = \rho_{BLK}/area$$
 ,  $R_{SC} = \rho_{SC}/area$  ,

$$I_{F 100 \text{ ns}} = J_{F}X \text{ area}$$

(8) Calculate power to damage for pulse duration t:

$$P_{D} = \left[ V_{BDC} \frac{I_{F} 100 \text{ ns}}{3.162} + \frac{I_{F}^{2} 100 \text{ ns}}{10} \left( R_{SC} + R_{BLK} \right) \right] / 1000t^{0.5} .$$

## 3. RESULTS

Appendix A lists a program used to implement the AFWL model, along with the input and resultant data. The model predictions are presented in figure 1 as  $\frac{1}{2}$ 

$$P_X/P$$
 , for  $P_X \ge P$  ,

$$P/P_X$$
 , for  $P > P_X$  ,

where

 $P_{\chi}$  = experimental power to damage,

P = corresponding predicted value,

as a function of the percentage confidence level. The percentage confidence level is defined as the percentage of data points with a ratio less than or equal to the given value. The envelope defined by the five priority models is plotted in figure 2 along with the predictions of the junction capacitance damage model for comparison and a plot of the scatter in the experimental data. The scatter in the experimental data is the ratio of the power to damage for the individual devices and the experimentally defined damage curve presented in the mode previously indicated for the AFWL model predictions. experimental data base used for this projection includes but is larger than that indicated in appendix A. The total base of 822 devices comprised a test population of 82 P-N junction types. This population includes both germanium devices and specialty devices for which AFWL model data are unavailable.

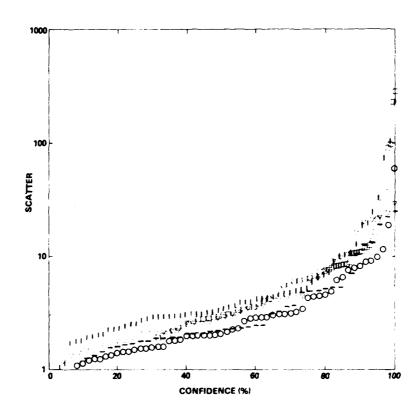


Figure 1. Percentage confidence level versus scatter in data for AFWL model:  $0 = \text{priority 1}, \square = \text{priority 2}, \triangledown = \text{priority 3}, | = \text{priority 4}, \text{ and } - = \text{priority 5}.$ 

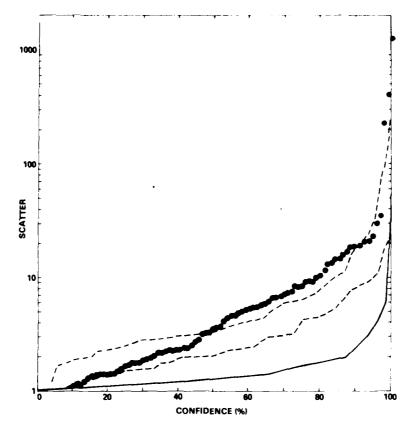


Figure 2. Percentage confidence level versus scatter in data for junction capacitance damage model (solid circles), limits of AFWL damage model (dashed curve), and experimental data (solid curve).

# 4. CONCLUSION AND DISCUSSION

At high confidence levels, the AFWL model represents approximately a doubled improvement over the junction capacitance damage model based on the device population employed in this study. One note of caution: The AFWL model, like all previous damage models, is for junction reverse bias only. To project from reverse bias failure to failure under forward bias is fraught with great difficulties. Figure 3 is a histogram of the experimental ratio of power to failure for forward and for reverse bias. (All measurements were made at 0.1-, 1-, and  $10-\mu s$  pulse durations.) Previous studies have shown that, despite the generally higher power to failure for forward bias, damage is as likely

to occur under forward as under reverse conditions for circuits driven to the failure level,  $^{1/2}$  The uncertainty indicated in figure 3 must be included in the uncertainty of the damage model predictions in projecting damage characteristics to forward bias.

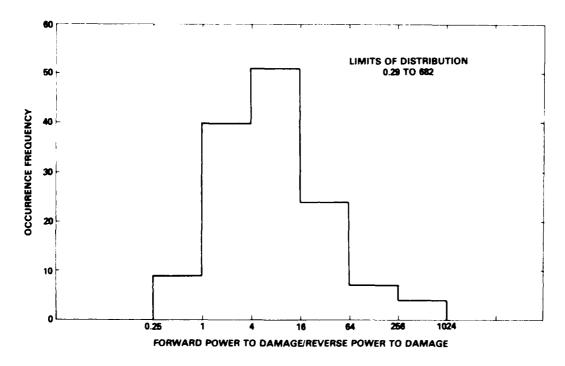


Figure 3. Histogram of ratio of experimental power to damage for forward and reverse junction bias for pulse durations in 0.1- to  $10-\mu s$  range for 78 percent of P-N junction types included in appendix A.

<sup>&</sup>lt;sup>1</sup>Michael J. Vrabel, EMP Assessment for Army Tactical Communications Systems: Transmission Systems Series No. 3 Radio Terminal Sets AN/TRC-112 and AN/TRC-121 (U), Harry Diamond Laboratories HDL-TR-1807 (May 1977). (SECRET-RESTRICTED DATA)

<sup>&</sup>lt;sup>2</sup>George Gornak et al, EMP Assessment for Army Tactical Communications Systems: Transmission Systems Series No. 1 Radio Terminal Set AN/TRC-145 (U), Harry Diamond Laboratories HDL-TR-1746 (February 1976). (SECRET-RESTRICTED DATA)

APPENDIX A.--AIR FORCE WEAPONS LABORATORY MODEL CODE, INPUT DATA, AND RESULTS OF PREDICTING BIPOLAR TRANSISTOR AND DIODE FAILURE FOR REVERSE JUNCTION BIAS

```
DAT(1.N)=-1: DIODE JUNCTION, O: C-B JUNCTION, 1: E-B JUNCTION
 DAT(2.N)=BREAKDOWN VOLTAGE (V)
 DATIS, N) = DIODE CAPACITANCE (PF), DEFAULT VALUE=0
 DAT(4.N)=C-B CAPACITANCE, DEFAULT VALUE=0
 DATIS.NI= E-B CAPACITANCE (PF), DEFAULT VALUE=0
 DAT(6.N)=MAXIMUM RATED CULLECTUR OR DIDDE CURRENTIAL
 DAT(7.N)=JUNCTION-TO -CASE THERMAL RESISTANCE (THETA JC) (C/W)
 DAT(8.N)=JUNCTION-TO-AMBIENT THERMAL RESISTANCE(THETA JA) (C/W)
 DAT(9.N)=BREAKDOWN VOLTAGE FOR C-B FOR EMITTER DATA
 DAT(10, N) = EXPERIMENTAL POWER TO CAMAGE AT O.1US
 DAT(11, N)=EXPERIMENTAL POWER TO LAMAGE AT 1 US
 DAT(12, N) = EXPERIMENTAL POWER TO CAMAGE AT 10 US
     DIMENSION DATTIZ,68), DOPE(68), BV(68), RHOSC(68), RHOBLK(68)
     DIMENSION FAILI168), AREA(5,68), RBLK15,68), RSC(5,68), CUP(5,68)
     DIMENSION D(5,68), RATIO(5,3.68), BIG(5), MZ(5), NZ(5), SET(5)
     DIMENSION B(5,150), C(5,150), MY(5), RSULT(5,300)
     DIMENSION DEVICE(272), RAT(5.3,68)
    DIMENSION AVG(3,68), BB(200), CC(200), RSLT(400)
     NAMELIST/LISTA/DAT, DEVICE
     READ (5.LISTA)
     WRITE(6,1)
    FORMATIZOX . 1 OHBREAKDOWN . 10H
                                   DIQUE ,10H
                                                   C-B
    €10H E-B
                 ,10HCDLL. CURR, 10H THETA JC ,10H THETA JA ,
                                , 10HDA MAGE
                                               .10HDAMAGE
                 .10HDAMAGE
    £10H BV C-B
     WRITE16,21
                                            ,10H
    FORMATIZOX 10H VOLTAGE 10H
                                    CAP.
                                                   CAP.
                 ,10H
                                (2U1.0) HOI,XOE,
          CAP.
                        MAX.
                  .10H (10.US)
    £10H (1.0U5)
     WRITE(6,3)
    FORMAT (20 X . 10 H & VOLTS) . 10 H . 10 H . (AMP) . 1
                                    (PF)
                                            ,10H
                                                   (PF)
                               ,10H (C/WATT) ,10H (C/WATT)
    CIOH (VOLTS) -10H (WATTS) -10H (WATTS) -10H (WATTS)
     WRITE(6,4)
     FORMAT (2X)
    DO 201 N=1,65
     M=4+(N-1)+1
     MM =M + I
     MMM=MM+1
     MMMM =MMM+1
     WRITE(6,200)DEVICE(M), DEVICE(MM), DEVICE (MMM), DEVICE (MMMM),
    £{DAT (M,N),M=2,12]
200
    FORMAT(2X,4A4,8F10.3,3F10.2)
201
     CONTINUE
     DO 100 N=1,68
     IF(DAT(2,N).EQ.O.) GO TO 100
     DOPE (N)=44.49E+181+DAT (2.N)++(-1.5)
100
     CONT INUE
     DO 101 N=1,68
     IF(DOPE(N).EQ.O.) GO TO 101
     BY(N)=(4.07E+12)+(DQPE(N))++(-0.67)
101
     CONTINUE
     DO 102 N=1.68
     IF (DOPE (N) .EQ.O.) GO TO 102
     RHDSC(N)=(2.48E+25]+(DDPE(N))++(-1.8)
102 CONTINUE
     DD 103 N=1,68
     IF (DDPE(N) .EQ.Q.) 60 70 103
```

### APPENDIX A

```
RHOBLK(N) = (3.61E+10) of DDPE(N)) ++ (-0.81)
103
     CONT INUE
     DO 104 N=1.68
     1F(DAT(1,N))105,105,106
     FAILI(N) = (8.26E-11) + (DOPE(N)) ++ (0.88)
     60 TO 104
106
     FAILIAN) = (3.84E-11) * (DOPE(N) ) ** (0.88)
104
     CONT INUE
     DO 107 N=1,68
     IF (DAT(1,N)) 110,109,108
     AREA (1.N)=1.47*((2.3E-06)*DAT(5,N)*DAT(2,N)**0.67)**1.05
     AREA(2,N)=(6.34E-04)*(DAT(6,N))**0.82
     AREA (3,N) = (8.75E-03)*(2.E-06*DAT(4,N)*(DAT(9,N))**0.83)**0.58
     1F(DAT(7,N).EQ.O.) GO TO 150
     AREA (4,N) = (1.19E-2) = (DAT (7,N)) == (-0.94)
150
     1F(DAT(8,N).E4.0.) GD TD 107
     AREA (5.N) = 2.79 + DAT (8.N) + + (-1.7)
     60 TO 107
     1F(DAT(7,N).EQ.O.) GD TD 151
109
     AREA(1,N)=0.047+(DAT(7,N))++(-0.89)
151
     AREA (2,N) = (2.72E-03) *(DAT(6,N)) **(0.62)
     1F(DAT(8,N).EU.O.) GC TO 152
     AREA (3,N) = 3.63 * (DAT (8,N)) **(-1.47)
     AREA (4,N) = (1.13E-02) + (2.E-06+DAT (4,N)+DAT(2,N)++0.83) ++0.39
152
     GD TO 107
110
     AREA(1,N)=(8.1E-03)*DAT(6,N)**1.16
     AREA(2,N)=0.458*(2.E-06*DAT(3,N)*DAT(2,N)**0.83)**0.83
     1F(DAT(7.N).EQ.O.) GO TO 153
     AREA (3,N) = 0.489 *DAT (7,N) ** (-1.21)
153
     IF (DAT(8,N).EQ.O.) GO TO 107
     AREA (4,N) = 1.963 *DAT (8,N) ** (-1.32)
107
    CONTINUE
     DO 111 N=1,68
     DO 112 M=1.5
     IF (AREA (M.N) . EQ. 0. ) GO TO 112
     RBLK (M,N) = RHOBLK (N) / AREA (M,N)
     RSC(M,N)=RHOSC(N)/AREA(M,N)
     CUR(M, N) = FAILI(N) + AREA (M, N)
112
    CONTINUE
111
     CONTINUE
     DG 116 N=1.68
     DO 113 M=1.5
     D(M, N)=(BV(N)+(CUR(M,N)/3.162)+((CUR(M,N)++2)/10.)+
    & (RSC (M.N)+RBLK(M.N)))/1000.
113 CONTINUE
116
    CONTINUE
     DD 117 N=1.68
     DD 118 M=1,3
     DO 114 K=1,5
     MM =Q + M
     AM=M-1
     IF(D(K,N).EQ.O.) GO TO 114
     RATIDEK,M,N)=DATEMM,N)/(D(K,N)+3162.+(10.)++(-0.5+AM))
     RATEK,M.N)=RATID(K.M.N)
     IF (RATIO(K.M.N).EQ.O.) GO TO 114
     IF(RATIO(K.M.N).GE.1.) GO TO 114
     RATIO(K,M,N)=1./RATIO(K,M,N)
114
    CONTINUE
    CONTINUE
118
117
     CONTINUE
```

```
WRITE(6,15)
     FORMAT (2X////)
     WRITE(6,5)
     FURMATIZX, 123HRATIO OF EXPERIMENTAL POWER TO DAMAGE TO PREDICTED V
    EALUE FOR 0.1, 1.0, AND 10 USEC PULSE DURATIONS FOR FIVE PRIORITY M
    EDDEL S//)
     WRITE(6,6)
                    PRTY 1 ,12h
,12h PRTY 5 /)
                                       PRTY 2 ,12H
                                                       PRTY 3
     FORMAT(26X+12H PRTY 1
    HS13
           PRTY 4
     DO 312 L=1,3
     DO 311 N=1.65
     M = 4 + (N-1) + 1
     MM =M +1
     MMM=MM+1
     MMMM=MMM+1
     write(6,310)Device(M),Device(MM),Device(MMM),Device(MMMM),
    &(RAT(K,L,N),K=1,5)
310 FURMAT(10x,4A4,5F12.4)
    CONT INUE
311
     WRITE(6,313)
313 FORMAT(2X//)
312 CONTINUE
     DO 800 N=1.68
     DO 801 M=1.3
     AJ=0.
     DD 802 K=1.5
     AVG(M,N)=RATIO(K,M,N)+AVG(M,N)
     IF(RATIO(K.M.N).EQ.O.) GC TO 802
     AJ=1.+AJ
802 CONTINUE
     IF (AVG (M.N).EQ.O.) GO TO 801
     LAY(M,N)=AVG(M,N)/AJ
801
     CONTINUE
800
     CONTINUE
     DO 803 LL=1,200
     DD 804 N=1.68
     DO 805 M=1.3
     IF (A VG (M.N ) . EQ. 0.) GO TO 805
     IF (AVG(M.N.LE.BIGG) GD TO 805
     BIGG = AVG (H.N)
     MAVG =M
     NAVG =N
805 CONTINUE
804 CONTINUE
     NZAA=1+NZAA
     IF (SETT.EQ.1.) GO TO 806
     IF (BIGG.NE.O.) GO TO 806
     SETT =1.
     MVV=NZAA-1
     MAV=MVV
     CONTINUE
806
     BB(NZAA)=BIGG
     BIGG = 0.
     AVG(MAVG, NAVG) = 0.
803 CONTINUE
     DD 808 N=1,200
     BN =N -1
     AMV=MVV
     CC(N)=100.-BN+(100./ANV)
```

BOB CONTINUE

## APPENDIX A

```
MM =0
     DD 880 N=1.MVV
     AVERAG=BB (N)+AVERAG
880 CONTINUE
     AVERAG = AVERAG/AMV
     DB 809 N=1.MVV
     MM=1+MM
     RSLT (MM)=BB(N)
     MM=1+MM
     RSLT (MM)=CC(N)
809 CONTINUE
     DO 130 LL=1,150
     DO 123 N=1,68
     DB 124 M=1.3
     DD 120 K=1.5
     IF (RATID (K.M.N) . EQ.O.) GO TU 120
     JF(RATIO(K.M.N).LE.BIG(K)) GO TO 120
     BIG(K)=RATIO(K,M,N)
     MZ(K)=M
     NZ (K )=N
120 CONTINUE
124 CONTINUE
123 CONTINUE
     NZA=1+NZA
     DD 131 KK=1.5
     1F(SET(KK)-EQ.1.) 60 TO 131
     1F(B1G(KK).NE.O.) GB TO 131
     SET(KK)=1.
     MV (KK) =NZA-1
131 CONTINUE
     DO 132 KK=1,5
     B(KK,NZA)=BIG(KK)
     BIG(KK)=0.
132 CONTINUE
     DO 133 KK=1,5
     MZZ=MZ(KK)
     NZZ=NZ(KK)
     RATID(KK, MZZ, NZZ) = 0.
133
     CONT INUE
130 CONTINUE
     DO 140 N=1,150
     DG 135 K=1.5
     BN=N-1
     AHV=HV(K)
     C(K,N)=100.-BN*(100./(AMV+.0000001))
135 CONTINUE
140 CONTINUE
     DO 142 K=1,5
     MVV=MV(K)
     MM = O
     DO 141 N=1.MVV
     MM=1+MM
     RSULT(K,MH)=B(K,N)
     MM=1+MM
     RSULT (K, MM )=C(K,N)
141
    CONTINUE
142
     CONTINUE
     WRITE(6,11)
     FORMAT(2X////)
11
     WRITE(6,10)
```

```
10
     FORMATIZX, 128HRATIO EXPERIMENTAL AND PREDICTED POWER TO DAMAGE VS
    EPERCENTAGE CONFIDENCE LEVEL FUR ALL PULSE DURATIONS FOR FIVE PRIOR
    EITY MODELS//)
     DO 145 K=1.5
     MJV= (MV(K)+1)+2
     WRITE(6,146)(RSULT(K,M),M=1,MJV)
     FORMAT (5X, 2F9.2, 3X, 2F9.2, 3X, 2F9.2, 3X, 2F9.2, 2X, 2F9.2)
      WRITE(6,12)
     FORMAT(2X//)
12
145
     CONTINUE
      WRITE(6,810)
810 FORMAT(2X////)
     WRITE(6.811)
811 FORMATION, 124HRATIG OF EXPERIMENTAL AND PREDICTED POWER TO WAMAGE
    EVS PERCENTAGE CONFIDENCE LEVEL FOR AVERAGE VALUE OF FIVE PRIORITY
    EMDDELS//)
     Sof I+VAH)=VLM
     WRITE(6,146) (RSLT(M), M=1, MJV)
     WRITE(6,810)
     WRITE(6,881)AVERAG
     FORMAT (15%, 31HARITHMETIC MEAN UF ABOVE DATA = .F9.2)
      STOP
     END
//GD.SYSIN DD .
ELISTA DAT=0,120,0,11,0,.05,0,357.120,140,52,20,
1,33,0,0,9,.05,0,357,120,30,16,9,
0,250,0,16,0,.025,0,0,250,300,80,20,
1,27,0,0,9,.025,0,0,250,100,44,20,
0.54,0,17,0,0,0,1000,54,160,70,30.
1.7.0.0.22.0.0.1000.54.625.112.70.
0,200,0,4.3,0,.05,0,500,200,50,46,42,
1.10.2.0.0,5.3,.05.0,500,200,160.48,15,
0,107,0,142,0,1.5,0,345,107,115,72,44,
1,7.8,0,0,53,1.5,0,345,107,590,255,110,
0,45,0,8,0,.03,0,500,45,180,74,30,
1,5,0,0,0,.03,0,500,45,230,60,16,
0,108,0,57,0,0,0,476,108,10,10,10,
1,7,4,0,0,8,0,0,476,108,53,30,18,
0,93,0,18,0,.6,0,434,93,135,53,20.
1,8.5,0,0,23,.6,0,434,93,110,78,53,
0,107,0,15,0,.8,0,303,107,220,85,32,
1,7.3,0,0,31,.8,0,303,107,400,135,40,
-1,0,0,0,0,1,0,0,0,2800,2300,2100.
-1,0,0,0,0,0,0,0,0,4100,2700,1600,
-1, -64,0,0,0,0,0,0,0,6400,2700,1400,
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-1,115,5.7,0,0,.075,0,0,0,420,80,15,
-1,5.7,40,0,0,0,0,0,2300,340,83,
-1,154,0,0,0,0,0,0,0,3300,1350,510,
-1,18,2320,0,0,0,0,0,170000,53720,17000,
-1,0,0,0,0,2,0,0,0,3000,3000,3000,
-1.4.7.0.0.0.0.0.0.0.262446.83000.26244.
-1,6.8,0,0,0,0,0,0,0,130000,41079,13000,
-1,0,0,0,0,3,0,0,0,80000,25280,8000,
-1,0,0,0,0,1,0,132,0,6700,2117,670,
0.40,0,1,0,.04,0,909,40,120,16,12.4,
1.5.4.0.0.0.0.04.0.909.40.8.2.2.6..84,
0.87,0,0,0,1.5,15,0,87,1800,1000,500,
```

1.6.0.0.0.1.5.15.0.87.1300.440.230.

..

## APPENDIX A

```
0.120,0.0,0,6,2.4,0,120,7000,2300.700,
1,14,0,0,0,6,2.4,0,120,13000,3800.1300,
0.315.0.0.0.5.5.0.315.1200.370.120.
1.9.1.0.0.0.5.5.0.315.10000.2150.490.
0.36.0.6.0..2.9.500.36.170.50.14,
1.6.4.0.0.0.0.2.0.500.36.30.19.12.
0,30,0,.8,0,.03,0,909,30,47,17,6,
1.3.0.0.0.0.03.0.909.30.22.10.4.3.
0.40,0,5,0,.2,0,500,40,100,21,4.3,
1.5.0.0.0.0.2.0.500.40.52.31.5.20.
0,53,0,.58.0,.05,0,200,53,64,20,5.8,
1,7.1.0.0,.6,.05,0,200,53,22,10,4
0.123.0.25.0..5.0.222.123.3200.2100.1400.
1.8.8.0.0.0.5.0.222.123.750.340.160.
0.205.0.0.0.3.7.0.205.1700.1100.700.
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0,25,0,6,0,0,0,500,25,93,17,2.8,
1,5,0,0,0,0,0,500,25,50,18,6,8,
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-1,505,85,0,0,0,0,0,44,33.5,25
-1,3.3,350,0,0,0,0,0,0,153800,20000,2600,
-1,725,17,0,0,.4,0,0,1625,580,500,
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-1,1580,0,0,0,0,35,0,0,0,5700,2000,800,
DEVICE(1) =4H2N32,4H8A(C,4H-B) ,4H
4H2N32,4H8A(E,4H-B) ,4H
4H2N33,4H5 (-,4HB)
                    ,4H
4H2N33,4H5 (E-,4HB)
                    .4H
4H2N33,4H6:JA,4HN(C-,4HB)
4H2N33,4H6:JA,4HN (E-,4HB)
4H2N24,4H84(C,4H-B) ,4H
4H2 N24,4H84 (E,4H-B) ,4H
4H2N37,4H36(C,4H-B) ,4H
4H2N37,4H36(E,4H-B),4H
4H2N93,4H0{C-,4HB}
                    .4H
4H2N93,4H0(E-,4HB)
                    .4H
4H2N24,4H81(C,4H-B) ,4H
4H2N24,4H81(E,4H-B) ,4H
4H2N29,4H07A6,4HC-B),4H
4H2N29,4H07A(,4HE-B),4H
4H2N22,4H22A(,4HC-B),4H
4H2N22,4H22A(,4HE-B),4H
4H1N43,4H84
            ,4H
                    94H
4HF 591,4H1-34,4H65
                    .4H
4H1N81,4H6
             ,4H
                    ,4H
4HIN21,4HWE
            ,4H
                    ,4H
             ,4H
4H1 N9 1 ,4H4A
                     .4H
4H1 N75,4H2A
            .4H
                    .4H
4HPC11,4H5
             .4H
                     .4H
4H1 N30,4H26B:,4HJAN
                    ,4H
4H1N36,4H11 ,4H
                    ,4H
4H1 N39,4H95A ,4H
                    ,4H
4HIN30,4H16B ,4H
                    .4H
4H1 N41,4H41 ,4H
                    ,4H
```

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4H10D2,4H ,4H ,4H
4H2N2B,4H57(C,4H-B),4H
4HZN28,4H57(E,4H-B) ,4H
4H2N33,4H75(C,4H-B) ,4H
4H2N33,4H75(E,4H-B) ,4H
4H2N14,4H90:J,4HAN(C,4H-B)
4H2N14,4H90:J,4HANEE,4H-B)
4H2N35,4H84(C,4H-B) +4H
4H2N35,4H841E,4H-B) ,4H
4H2N28,4H94(C,4H-B) ,4H
4H2N28,4H94(E,4H-B) .4H
4H2N58,4H29(C.4H-B) .4H
4H2N58,4H291E,4H-81 ,4H
4H2N30,4H13:J,4HAN1E,4H-B)
4H2N30,4H13:1,4HAN1E,4H-B)
4HCA30,4H184C,4H-B) ,4H
4HCA30,4H181E,4H-B) ,4H
4H2N16,4H13:J.4HANEC,4H-B)
4H2N16,4H13:J,4HANEE,4H-P1
4H2N14,4H85:J,4HANEC,4H-B)
 CHENTA -4H85 = J. 4HANTE .4H-B)
 4H2N34,4H39(C,4H-B),4H
 4H2N34,4H39(E,4H-B) ,4H
 4H2N70,4H6:JA,4HN(C-,4HB)
 4H2N70,4H6:JA,4HN1E-,4HB)
                      ,4H
 4H1N25,4H80 .4H
 4H1N75,4H1A:J,4HAN
 4H1 N48,4H5B:J,4HAN
                     ,4H
 4H1 N29,4H91B: 4HJAN ,4H
4H1N30,4H25E:,4HJAN ,4H
                      ,4H
 4HM 010 ,4H54 ,4H
 4H1N74,4H6A:J,4HAN
                      ,4H
 4H1 N64,4H5 = JA,4HN
 4H1N12,4H02RA,4H=JAN,4H
 4H1N17.4H31A:,4HJAN ,4H
 EEND.
11
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	BREAKOUM	91010	<b>8</b> -0	£-8	COLL. CURR	THETA JE	THE TA JA	BV C-9	DAMAGE	DAMAGE	DAMAGE
	VOLTAGE (VOLTS)	CAP.	CAP.	GP.	HAX.	(C/MATT)	(C/WATT)	(VOLTS)	(0.1US)	(1.005)	(10.05) (WATTS)
2N320A(C-B)	120-000	00	11.000	0.0	050-0	0.0	357.000	120-000	140-00	52.00	20.00
	250-000	00	16.000	0-0	0.025	9 0	0-0	250-000	300.00	00-00	20.00
2N335(E-B)	27.000	0.0	0.0	000-6	0.025	0	0.0	250-000	100-00	44.00	20.00
CM 536 538 (C -8)	24-000	90	000-71	22-000		000	1000-000	4.5 000 000 000 000	25.00	112.00	10-07
•	200-000	0	4.300	0	0.050	0	200-000	200-002	50.00	4	45.00
2H24041E-0)	10.200	0.0	0.0	5-300	0.050	0	200,000	200.000	160-00	48-00	15.00
243736(C-B) 243736(F-B)	000-101	00	0.00	53.000	1.500	000	345-000	107-000	00-065	255.00	110,00
2N9 301C-B3	45.000	0	000-8	0	0.030	0	500.000	45.000	160.00	74-00	30.00
2N930 (E-B)	5.000	0.0	0.0	0.0	0.030	0	200,000	45-000	230.00	00-09	16.00
2N2481((-B)	108-000	000	57.000	000	0 0	0 0	476-000	108-000	00-01	00-01	
2N 2907A (C-B)	93.000	0	18.000	0.0	0.600	0	434.000	93.000	135.00	53.00	20.00
2N2907A1E-B)	•	0.0	0.0	<b>23.</b> 000	009-0	0.0	434 .000	93.000	110.00	78.00	53.00
2M22224(L-6)	000-101	•	20.0	000			000-606	107.000	00-004	135.00	00.04
•		0	0	0.0	1.000	0	0.0	0.0	2800.00	2300.00	2100-00
F 5911 -3465	0.0	0.0	0.0	0-0	0.0	0	0.0	0.0	4100.00	2700-00	1600-00
91 921	0 - 6 - 6	0.0	0 0		9 6			0 0	000000000000000000000000000000000000000	00.00	
149144	115.000	5.700		0	0.075	9	0	0	420.00	00.08	15.00
14752A	5.700	000-04	0.0	0.0	0.0	0.0	0.0	0.0	2300 -00	340.00	63.00
PC115	154_000	000-0262	000	0 0		0 0	000	0 0	3300,000,000	1350-00	7000-000
•	0	0.0	0	0	2.000	0	0	0.0	3000 000	3000.00	3000-00
1 H3995A	4.700	0.0	0.0	0.0	0.0	0-0	0.0	0	262446.00	83000-00	26244 -00
18 30166	•	000	000	000	0	9 0	9 0	200	0000051	25.26.00	000000000000000000000000000000000000000
1002	0	0		0	000	0	132.000	0	6 700 .00	2117.00	670.00
2N2857((-8)	000-04	0.0	1.000	0.0	0-040	0.0	000-606	000-04	120.00	16.00	12-40
2N 2057 (F-0)	004.2	0 0	0 0	0 0	0 0 0 0	0 0	000-606	40-000	9 00 00 00 00 00 00 00 00 00 00 00 00 00	2000	
12N 3375(E-B)	9	0	0	0	1.500	15-000	0	97-000	1300.00	00.044	230.00
3N14902JAN6C-81	120-000	0.0	0.0	0.0	000-9	2.400	0.0	120.000	7000 .00	2300.00	700-00
ZN 14901 JAR (E -6)	14.000	0.0	0.0	0.0	000	2-400	0.0	120-000	13000 000	3800.00	1300-00
2N 35041 F-B)	9-100	000	0.0	0	2-000	2-000	900	315,000	00-00001	2150.00	00-04
2N28941C-81	36.000	0	000.9	0.0	0.200	0.0	500.000	36.000	170.00	20.00	14-00
2N2894(E-B)	904.00	0.0	0.0	0	0-200	0	200-000	36.000	30 00	00.66	12.00
19-1)4795N7	000.08	9 6		•	0.0		000-606	30-000	200		
2N30131JAN(C-8)	00000	0	2.000	0	0.200	0	200-000	000-04	100-00	21.00	4.30
2N3013: JAN(E-B)	2.000	0.0	0.0	0-0	0.200	0.0	200 000	40-000	52.00	31.50	20.00
CA3016(C-R)	53.000	0.0	0.580	0.0	050-0	0	200-002	53-000	64-00	20.00	000
CA 5018 (E-5)	000-821	0 0	25.000		000		222-000	000-656	00-002E	2001	
7	000.8	0	0.0	0	0.500	0	222.000	123.000	750-00	340.00	160-00
2N14B51JANIC-B)	205.000	0.0	0.0	0.0	3.000	1.000	0.0	205-000	1700.00	1100.00	100-00
2N1485:JAN(E-B)	16.000	0.0	0 9	0 0	3.000	7.000	0 0	205-000	2900000	30000 000	3100-001
	004.6	0	0	0	000	36-000	0	575.000	2200-00	420.00	00-001
ž	25.000	0.0	000-9	0-0	0.0	0.0	200 000	25.000	93.00	17.00	2.80
2N706: JAN (E-B)	2000	0.0	0-0	0.0	0.0	0.0	200 000	72-000	\$0 °00	16.00	9

1825181 JAN 1875181 JAN 186551 JAN	536.000	265.000	000	0000	0.200	0000	0000	0000	25500.00	\$3120.00 2500.00 435.00	17000 -00 240 -00 100 -00
18299182JAN 18302582JAN MC1054	16.000	310.000	000		900	900	900		000001	14000 .00 33.50	1400-00
1	3.300	350.000	00	00	0.0	00	00	00	153800 .00	20000-00	2600 ±00 500 ±00
1N1 202RA: JAN 1N1 731A 2 JAN	514.000	00	000	00	0.350	00	00	00	\$ 700 °00 \$ 700 °00	2000.00	100 00 00 00 00

RATIO OF EXPERIMENTAL POWER TO DAMAGE TO PREDICTED VALUE FOR 0.1. 1.0. AND 10 USEC PULSE DURATIONS FOR FIVE PRICRITY MODELS

	PRTY 1	PRTY 2	PRTY 3	PRIV 4	PATY 5
1284 (C-B)	0.0	8064-0	0.3246	0.2566	0.0
2N32BA(E-B)	0 -2 935	1.1214	0.0	0	0-4775
2N335(C-0)	0.0	2.1016	0	0.4870	0
2N335(E-B)	1.024	6.0125	0.0	0.0	0
2N3361JAN (C-B)	0.0	0.0	1 -2035	0.2287	0
2N336 2 JAN (E -B)	2.7970	0.0	0	0*0	22.5051
1 N S 4 B 4 (C - B)	0.0	0.2111	0.2291	0.1349	000
N2484 [ E-B ]	3.2438	3.1116	0.0	0.0	2.3489
N3736 (C-B)	0	0.0468	0.2426	0.0772	0
2 N3 736 (E-B)	1 .05 83	0.5799	0.0	0	3.7889
2N9 30 (C-B)	0.0	0.5655	17 >> 0	0.3349	0.0
2N930(E-B)	0.0	3.8508	0.0	0	1.9122
2N2481 (C-8)	0.0	0.0	0.0340	9600-0	0
2 N2481 (E-B)	96890	0	0.0	0	0.5647
2N2907A (C -8)	0.0	0.0917	0.3774	9007-0	0.0
N2937A (E -8)	0.4763	0.2446	0	0.0	1.1137
2N2222A(C-8)	0	0.1323	0.3834	0.3547	0
N2222A (E-B)	1 -2 536	0.6251	0.0	0.0	1.9563
N4.384	0.0	0	0	0.0	0-0
5911-3465	0.0	0.0	0.0	0.0	0
N8 16	0.0	0.0	0.0	0.0	0
N21 WE	0.0	0.0	0	0.0	0.0
N914A	1.5322	92590	0.0	0.0	0
N752A	0.0	0.7561	0.0	0	0
(115	0.0	0.0	0.0	0.0	0.0
130268:JAN	0.0	2 .4439	0	0.0	0
N3611	0.0	0.0	0.0	0.0	0
N3995A	0.0	0.0	0.0	0.0	0.0
N30168	0.0	0.0	0.0	0	0
#4141	0.0	0.0	0.0	0.0	0.0
200	0.0	0.0	0	0	0
N28571C-81	0.0	0.2968	0-6753	0.4912	0.0
N28571E-83	0.0	0.1162	0.0	0	0.2018
N33751(-B)	0.5589	0.6745	0.0	0	0
N3375 (E-B)	0.0	1 .0331	0.0	0.9786	0
N1490: JANIC -B)	0.4832	1.2612	0.0	0.0	9
N1490 2 JAN (E-B)	0.0	6.1278	0.0	3.2309	0.0
N3584 (C-B)	0 -2236	0.3401	0.0	0.0	0
M3564 (E-B)	0.0	4 -1091	0.0	3.7194	0
2N2894 (C-R)	0.0	0.1465	0.3755	0.3383	0

2N2894 (E-B)	0 0	0.1313	0.0	0*0	0.3090
316785	0.0	0.1184	0.2253	0 -1963	9
28582946-83	<b>0</b> 0	67770	0.0		9506.0
	90	0.1837	0	•	0.4323
9-5	0	0.1587	0-0448	0.3406	0
CA3018(E-B)	4.3283	0.3267		9	0.0519
)	0	2 -7 16 4	3.7253	4-2633	000
(G-)12773585187	26.00	0.5718	0	90	è
JANCE.	0	279.2483	0.0	228.1203	0.0
2	27 0 0 0	0.0728	000	9"	<b>0</b>
2M30A: JAM (C -R )	90	0-0	0.1657	0-1676	200
AN CE	0	0	1	; 9	0-4157
N2580	2.9173	0.0	0-0	0.0	0.0
	٥.	1.6703	0	0	o 0
47.46	10.0	3.4068			200
	0	10.6319	0	0	0
	0-0	0 .0043	0-0	0.0	0.0
1 N 7 4 6 A : JA N	9	6 -544 3	0.0	0.0	0.0
T T T	٠.	۶. و	0	0	0
1 N 1 7 3 1 A : JAN	8-2311	00	90	000	90
2N32BA (C-B)	0	•	0.3813	0.3013	0
1	0.4950	•	0.0	٠ <u>.</u>	0.8052
2N335(C-B)	0.0	1.7722	0.0	0.4107	0.0
9	•	•		9	9 0
2 N 3 3 6 5 J AN (C - E )	0-0	9 0	0 0 0	401000	12.7532
9-5			0.6664	0.3925	
2N2404 (E-B)	3.0773	2.9519	9		2.2284
۷.	٠,	0.0927	0.4803	0.1528	و ا
2N37361E-B)	1 -4465	567.	9	2 4	5-1785
	30	3-1767	'n	******	1.5774
	0	9	0-1075	0.0303	9
	1.2343	0	0	٥.	1 -0101
=	<b>٩</b>	0.1139	0.4685	0-2491	٠,
2422224 (C - B )		146	0.0	0.0 Fre4.0	0-0
2 N2 2 2 2 A (E -B)	1.3380		9	9	2 -08 79
	0	0.0	0.0	0.0	0.0
F 5911-3465	0,0	0	0	0	0
9.02.	0,0	90	9 6	90	000
45.03.	0.9229	0.3899	0	0	90
1 N 7 5 2 A	9	353	0	0	0
	0.0	0	0	0.0	<b>0</b>
1 N30268 : JAN	0	2.4421	0,0	<b>0</b>	00
INSELL	2 0		9 0	200	200
1830168	200	90	000	000	000
1 N6161	0	•	0.0		0
20	0.0	0		0	0 0
2N28571C-B)	•	0.1251	i	0-2071	

2 W 2 B 5 7 ( F - R )		-	0-0		0.2023
2N3375 (C-B)	0.9839	; =	0	0	q
2N33751E-8)	0		0.0	1.0474	0.0
=	0.5020	1.3104	0	9	0
SJANGE	•	5.6643	0.0	2.9865	0.0
ĭ	0.2160	0.3316	0.0	Q.	0.0
2N3584 (F-8)	00	2.7937	9	2.5288	0
:	200	79576	74460	100	
: =	0	0.1354	0.2577	0.2245	9
~	0	0.3205	0	0	96690
# .	0.0	90900	0.1552	0.1451	9
E JANCE	0 0	0.3520	9	٠,	•
	0.0	8951.0	5 4 0 0	0.5363	7750
2 JANCC	9	5.6372	7.7308	8 -84 74	? 9
: JANCE	0	2.8485	0-0	0	3.5732
281465: JANIC -8)	0.7561	1.1699	00	0.0	0
16-6)	0.1119	• 0	0	3	200
2N3439 (E-R)	0	3.0864	0	774	0
JANIC	0.0	0.0	0.0958	0.0971	9
JAN (E-B	o i	0.0	0.0	0	0.4732
4	26.19.0	42.6		9 6	9 0
- 00		1.5309	0	0	0
8 :JA	0	3.6042	0.0	0	0
1 N30258 tjan	•	3.3621	0.0	0	0
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2N328A (C-B)	0 0	٦.	0.4637	0.3665	0
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N2484	9	1.7731	1.9242	1.1331	9
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N 3736 (	1.9731	Ö	0.0	, 9	7.040
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2N2222A1E -B)	1 -2 536	3.	0.0	0-0	1.9563
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2h2857 (C-8)	0	0.3067	0.6978	0.5076	0.0
2 N285716-01	0.0	0.1190	0.0	0.0	0.2067
2N3375[(-8]	1.5526	1.8736	0.0	0.0	0.0
2 N3375 LE-83	0	1.8278	0.0	1.7314	0
241490: JANIC -61	0 -4832	1.2612	0.0	0	0
2 N 1 4 9 0 2 JA N ( F - B )	0	6.1278	0.0	3 -2 30 9	<b>0</b>
2N3584 (C-8)	0.2236	0.3401	0	0.0	0
2 N3584 (E-B)	0.0	2.0135	0.0	1.8225	0.0
2N2894 (C-B)	0.0	0.1206	0 -3092	0.2786	0
2 N20941E-B)	0.0	0.524	0.0	0	1 .2361
2N58291C-B3	0.0	0.1511	0.2877	0.2505	0
2 N5 B 29 (F-R)	0	0.4358	0.0	0.0	0.597
2N3013:JANIC-B	0.0	2660.0	0-1005	0.0940	0
2 N3013: JAN(F-B)	0.0	0.7067	0.0	0	1.6628
CA30181C-B)	0.0	0-1438	9040-0	0.3086	0
CA3018 (E-8)	7.86 %	0.5940	0.0	0.0	460.0
J	0.0	11.8843	16.2980	18.6519	0
2NI613: JANIE-B)	0.0	4 .2389	0.0	<b>0</b>	5.317
·	1.5216	2.3543	0.0	0.0	0
2 N1 485 : JAN(F-B)	0.0	29.8507	0.0	24.3853	0
2N34391C-BJ	0.1311	0.0933	0	0	0
2 N3439 (E-B)	0.0	2.8335	0.0	4 .3832	0
2N 706: JAN (C -8)	0.0	0.0	6690-0	0.0506	0
2 N 7 06 : JAN (E-6)	0.0	0.0	0.0	0	0.565
1N2580	2.9173	0.0	0	0.0	0
1 N751A : JAN	0.0	0.1572	0.0	<b>0</b> •0	0
1 N 4 6 5 B : JA N	1.5861	1.1129	0.0	0.0	0
1 N29918 2JAN	0.0	3.6068	0.0	0.0	o 0
1N30258:JAN	0.0	1.0632	0.0	0.0	0
M 01054	0.0	0.0246	0.0	0.0	0
1 N746A = JAN	0.0	1.1063	0.0	0.0	0
1 N645 : JAN	4-8762	1.6311	0	0.0	0
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